

20V, 350mA, Rail-to-Rail Operational Amplifier

General Description

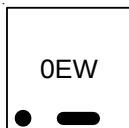
The RT9148/9 consists of a low power, high slew rate, single supply rail-to-rail input and output operational amplifier. The RT9148 contains a single amplifier and RT9149 contains two amplifiers in one package.

The RT9148/9 has a high slew rate (35V/μs), 350mA peak output current and offset voltage below 15mV. The RT9148/9 is ideal for Thin Film Transistor Liquid Crystal Displays (TFT-LCD).

The RT9148 is available in the WDFN-6L 2x2, TSOT-23-5 and UDFN-6L 2x2 packages. The RT9149 is available in the WDFN-8L 3x3 package. The RT9148/9 are specified for operation over the full temperature range from -40°C to 85°C.

Marking Information

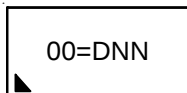
RT9148ZQW



0E : Product Code

W : Date Code

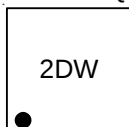
RT9148GJ5



00 : Product Code

DNN : Date Code

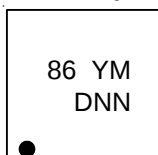
RT9148GQU



2D : Product Code

W : Date Code

RT9149ZQW



86 : Product Code

YMDNN : Date Code

Features

- Rail-to-Rail Output Swing
- Supply Voltage : 6V to 20V
- Peak Output Current : 350mA
- High Slew Rate : 35V/μs
- Unity Gain Stable
- RoHS Compliant and Halogen Free

Applications

- TFT LCD Panels
- Notebook Computers
- Monitors
- LCD TVs

Ordering Information

RT9148 □ □

Package Type

QW : WDFN-6L 2x2 (W-Type)

Lead Plating System

Z : ECO (Ecological Element with Halogen Free and Pb free)

RT9148 □ □

Package Type

J5 : TSOT-23-5

QU : UDFN-6L 2x2 (U-Type)

Lead Plating System

G : Green (Halogen Free and Pb Free)

RT9149 □ □

Package Type

QW : WDFN-8L 3x3 (W-Type)

Lead Plating System

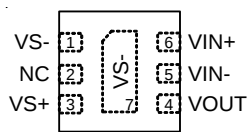
Z : ECO (Ecological Element with Halogen Free and Pb free)

Note :

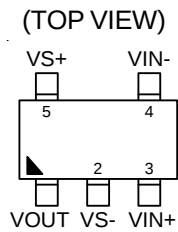
Richtek products are :

- ▶ RoHS compliant and compatible with the current requirements of IPC/JEDEC J-STD-020.
- ▶ Suitable for use in SnPb or Pb-free soldering processes.

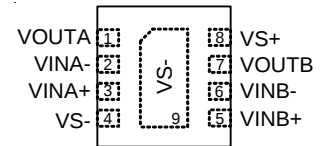
Pin Configurations



WDFN-6L 2x2 / UDFN-6L 2x2
RT9148

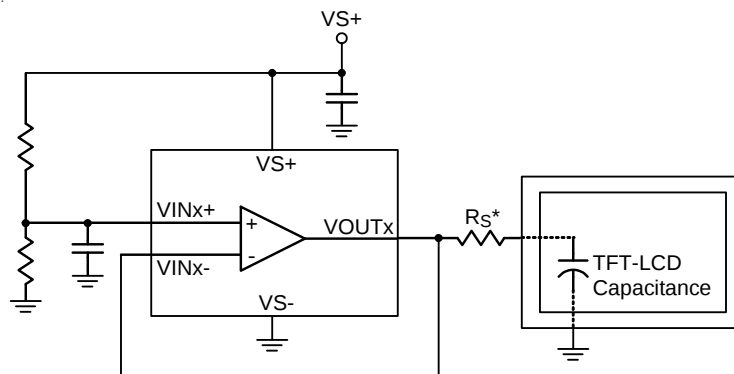


TSOT-23-5
RT9148



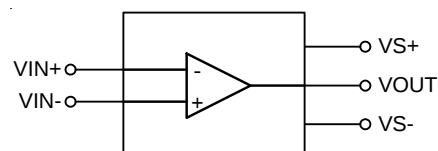
WDFN-8L 3x3
RT9149

Typical Application Circuit

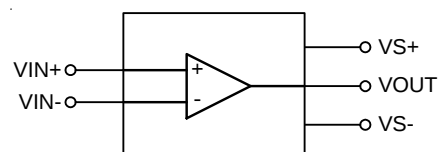


*: R_S may be needed for some applications.

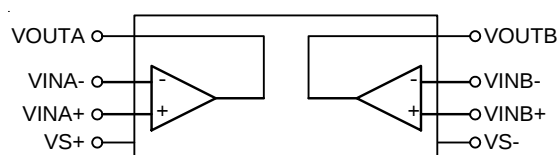
Function Block Diagram



WDFN-6L 2x2 / UDFN-6L 2x2
RT9148



TSOT-23-5
RT9148



WDFN-8L 3x3
RT9149

Functional Pin Description

RT9148

Pin No.		Pin Name	Pin Function
WDFN-6L 2x2, UDFN-6L 2x2	TSOT-23-5		
1, 7 (Exposed Pad)	2	VS–	Negative Supply Input.
2	--	NC	No Internal Connection.
3	5	VS+	Positive Supply Input.
4	1	VOU	Output.
5	4	VIN–	Negative Input.
6	3	VIN+	Positive Input.

RT9149

Pin No.	Pin Name	Pin Function
1	VOU	Output of Amplifier A.
2	VIN–	Negative Input of Amplifier A.
3	VIN+	Positive Input of Amplifier A.
4, 9 (Exposed Pad)	VS–	Negative Supply Input.
5	VINB+	Positive Input of Amplifier B.
6	VINB–	Negative Input of Amplifier B.
7	VOUB	Output of Amplifier B.
8	VS+	Positive Supply Input.

Absolute Maximum Ratings (Note 1)

• Supply Voltage, (VS+ to VS-) -----	24V
• VINx+, VINx- to VS -----	-0.3V to 24V
• VINx+ to VINx- -----	±5V
• Power Dissipation, PD @ TA = 25°C	
WDFN-6L 2x2 -----	2.1W
TSOT-23-5 -----	0.43W
UDFN-6L 2x2 -----	2.09W
WDFN-8L 3x3 -----	3.22W
• Package Thermal Resistance (Note 2)	
WDFN-6L 2x2, θ_{JA} -----	47.5°C/W
TSOT-23-5, θ_{JA} -----	230.6°C/W
UDFN-6L 2x2, θ_{JA} -----	47.7°C/W
WDFN-8L 3x3, θ_{JA} -----	31°C/W
WDFN-8L 3x3, θ_{JC} -----	8°C/W
• Lead Temperature (Soldering, 10 sec.) -----	260°C
• Junction Temperature -----	150°C
• Storage Temperature Range -----	-65°C to 150°C
• ESD Susceptibility (Note 3)	
HBM (Human Body Model) -----	2kV
MM (Machine Model) -----	200V

Recommended Operating Conditions (Note 4)

• Supply Voltage, VS- = 0V, VS+ -----	6V to 20V
• Junction Temperature Range -----	-40°C to 125°C
• Ambient Temperature Range -----	-40°C to 85°C

Electrical Characteristics

(VS+ = 16V, VS- = 0V, VINx+ = VOUTx = VS+ / 2, RL = 10k Ω and CL = 10pF, TA = 25°C, unless otherwise specified)

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
Input Characteristics						
Input Offset Voltage	VOS	VCM = VS+ / 2	--	2	15	mV
Input Bias Current	IB	VCM = VS+ / 2	--	2	50	nA
Load Regulation	ΔV_{LOAD}	IL = 0 to -80mA	--	0.1	--	mV/mA
		IL = 0 to 80mA	--	-0.1	--	
Common Mode Input Range	CMIR		0.5	--	VS+ -0.5	V
Common Mode Rejection Ratio	CMRR	0.5V ≤ VOUTx ≤ VS+ - 0.5V	--	95	--	dB
Open Loop Gain	AVOL	0.5V ≤ VOUTx ≤ VS+ - 0.5V	--	118	--	dB

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
Output Characteristics						
Output Swing Low	V_{OL}	$I_L = -50\text{mA}$	--	0.6	1.5	V
Output Swing High	V_{OH}	$I_L = 50\text{mA}$	$V_{S+} - 1.5$	$V_{S+} - 0.3$	--	V
Transient Peak Output Current	I_{PK}		300	350	400	mA
Power Supply						
Power Supply Rejection Ratio	PSRR	$V_{S+} = 6\text{V to } 20\text{V}$, $V_{CM} = V_{OUTX} = V_{S+} / 2$	--	96	--	dB
Quiescent Current	I_{DD}	No Load	--	4	--	mA
Dynamic Performance						
Slew Rate	SR	4V step, 20% to 80%, $A_V = 1$	--	35	--	V/ μs
Setting to $\pm 0.1\%$ ($A_V = 1$)	t_S	$A_V = 1$, $V_{OUTX} = 2\text{V step}$ $R_L = 10\text{k}\Omega$, $C_L = 10\text{pF}$	--	270	--	ns
-3dB Bandwidth	BW	$R_L = 10\text{k}\Omega$, $C_L = 10\text{pF}$	--	16	--	MHz
Gain-Bandwidth Product	GBWP	$R_L = 10\text{k}\Omega$, $C_L = 10\text{pF}$	--	12	--	MHz
Phase Margin	PM	$R_L = 10\text{k}\Omega$, $C_L = 10\text{pF}$	--	50°	--	--

Note 1. Stresses beyond those listed "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions may affect device reliability.

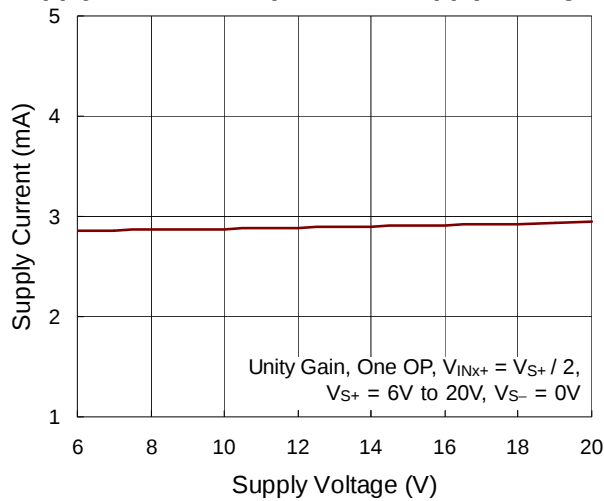
Note 2. θ_{JA} is measured at $T_A = 25^\circ\text{C}$ on a high effective thermal conductivity four-layer test board per JEDEC 51-7. θ_{JC} is measured at the exposed pad of the package.

Note 3. Devices are ESD sensitive. Handling precaution is recommended.

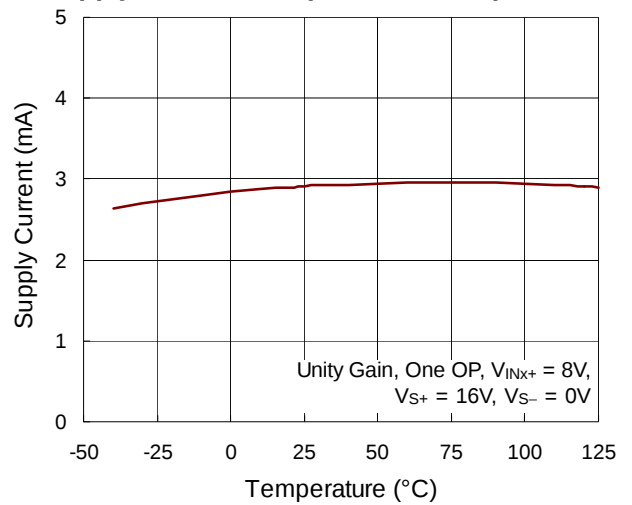
Note 4. The device is not guaranteed to function outside its operating conditions.

Typical Operating Characteristics

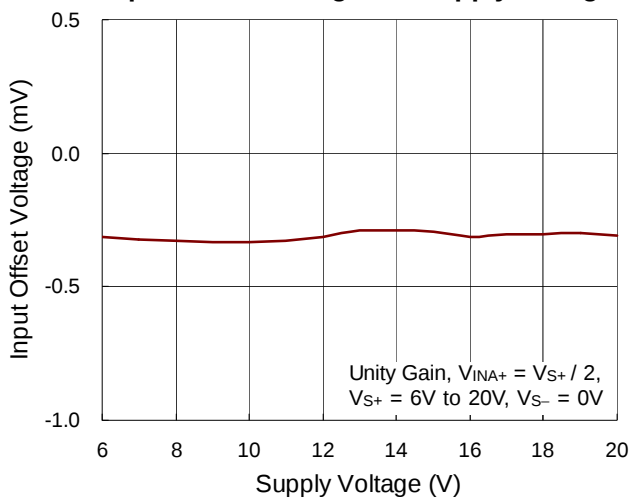
Supply Current / Amplifier vs. Supply Voltage



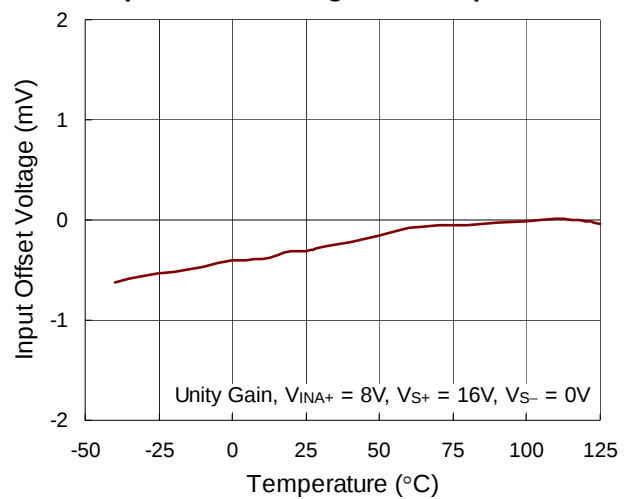
Supply Current / Amplifier vs. Temperature



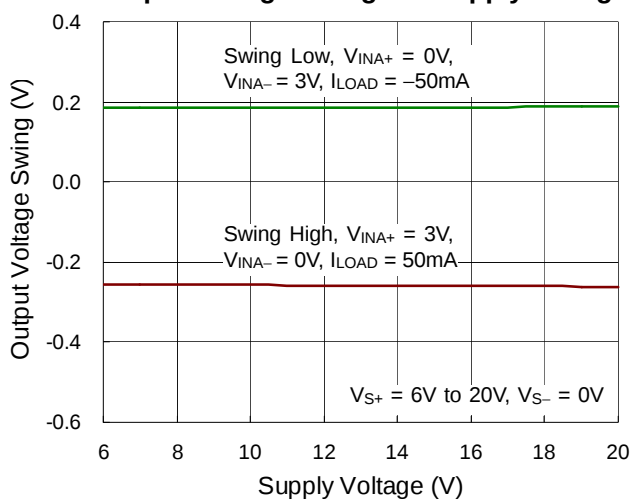
Input Offset Voltage vs. Supply Voltage



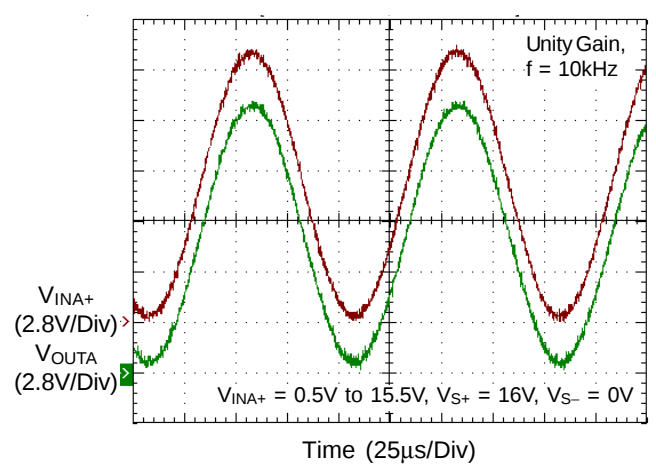
Input Offset Voltage vs. Temperature



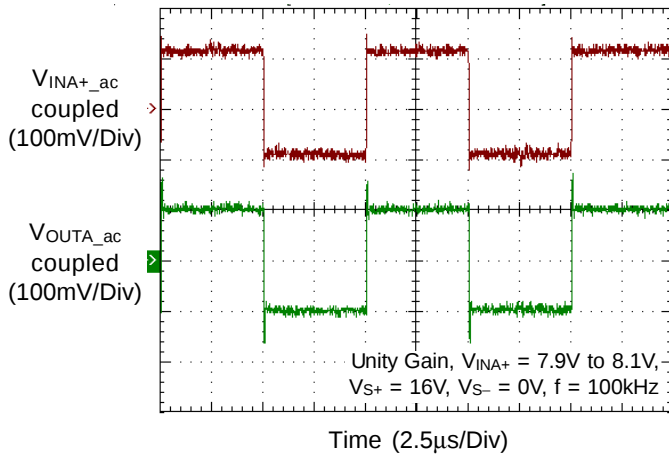
Output Voltage Swing vs. Supply Voltage



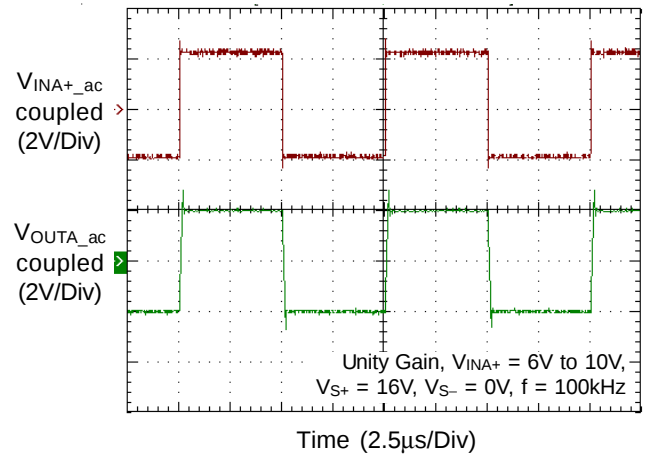
Rail to Rail



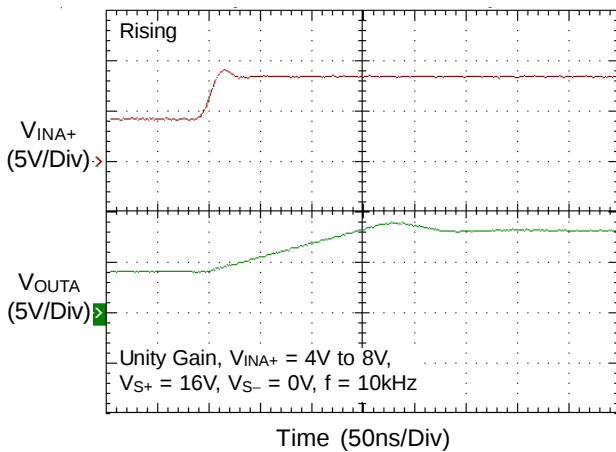
Small Signal Response



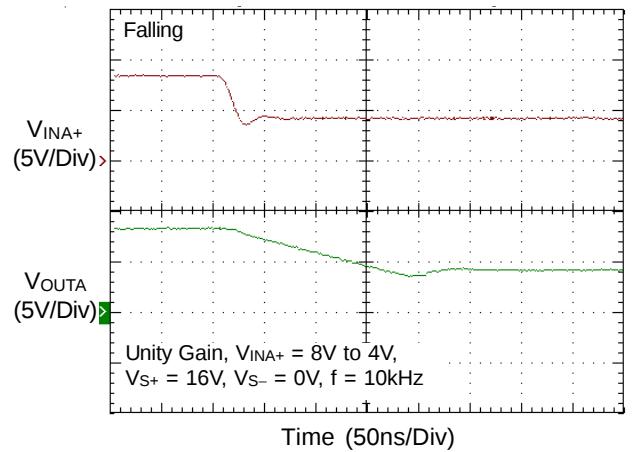
Large Signal Response



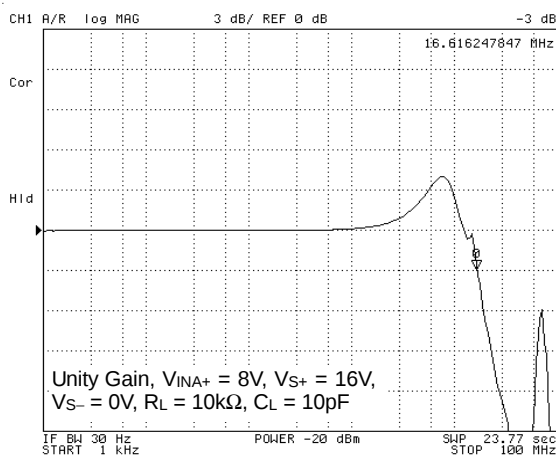
Slew Rate



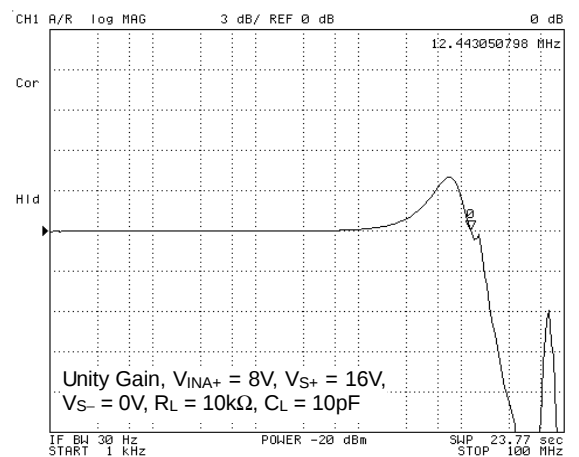
Slew Rate



-3dB Bandwidth



Gain Bandwidth Product



Applications Information

The RT9148/9 is a high performance operational amplifier capable of driving large loads for different applications. A high slew rates, rail-to-rail input and output capability, and low power consumption are the features which make the RT9148/9 ideal for LCD applications. The RT9148/9 also has wide bandwidth and phase margin to drive a load with 10k Ω resistance and 10pF capacitance.

Operating Voltage

The RT9148/9 total supply voltage range is guaranteed from 6V to 20V. The specifications are stable over both the full supply range and operating temperatures from -40°C to 85°C. The output swing of the RT9148/9 typically extends to within 1.5V of positive/negative supply rails with 50mA load current source/sink. Decreasing the load current will obtain an output swing even closer to the supply rails.

Short Circuit Condition

An internal short circuit protection is implemented to protect the device from output short circuit. The RT9148/9 limits the short circuit current to $\pm 350\text{mA}$ if the output is directly shorted to positive/negative supply rails.

LCD Panel Applications

The RT9148/9 is mainly designed for LCD V-com buffer. The operational amplifier has 350mA instantaneous source/sink peak current.

Thermal Considerations

For continuous operation, do not exceed absolute maximum junction temperature. The maximum power dissipation depends on the thermal resistance of the IC package, PCB layout, rate of surrounding airflow, and difference between junction and ambient temperature. The maximum power dissipation can be calculated by the following formula :

$$P_{D(\text{MAX})} = (T_{J(\text{MAX})} - T_A) / \theta_{JA}$$

where $T_{J(\text{MAX})}$ is the maximum junction temperature, T_A is the ambient temperature, and θ_{JA} is the junction to ambient thermal resistance.

For recommended operating condition specifications, the maximum junction temperature is 125°C. The junction to ambient thermal resistance, θ_{JA} , is layout dependent. For WDFN-6L 2x2 packages, the thermal resistance, θ_{JA} , is 47.5°C/W on a standard JEDEC 51-7 four-layer thermal test board. For TSOT-23-5 packages, the thermal resistance, θ_{JA} , is 230.6°C/W on a standard JEDEC 51-7 four-layer thermal test board. For UDFN-6L 2x2 packages, the thermal resistance, θ_{JA} , is 47.7°C/W on a standard JEDEC 51-7 four-layer thermal test board. For WDFN-8L 3x3 packages, the thermal resistance, θ_{JA} , is 31°C/W on a standard JEDEC 51-7 four-layer thermal test board. The maximum power dissipation at $T_A = 25^\circ\text{C}$ can be calculated by the following formula :

$$P_{D(\text{MAX})} = (125^\circ\text{C} - 25^\circ\text{C}) / (47.5^\circ\text{C/W}) = 2.1\text{W for WDFN-6L 2x2 package}$$

$$P_{D(\text{MAX})} = (125^\circ\text{C} - 25^\circ\text{C}) / (230.6^\circ\text{C/W}) = 0.43\text{W for TSOT-23-5 package}$$

$$P_{D(\text{MAX})} = (125^\circ\text{C} - 25^\circ\text{C}) / (47.7^\circ\text{C/W}) = 2.09\text{W for WDFN-6L 2x2 package}$$

$$P_{D(\text{MAX})} = (125^\circ\text{C} - 25^\circ\text{C}) / (31^\circ\text{C/W}) = 3.22\text{W for WDFN-8L 3x3 package}$$

The maximum power dissipation depends on the operating ambient temperature for fixed $T_{J(\text{MAX})}$ and thermal resistance, θ_{JA} . The derating curve in Figure 1 allows the designer to see the effect of rising ambient temperature on the maximum power dissipation.

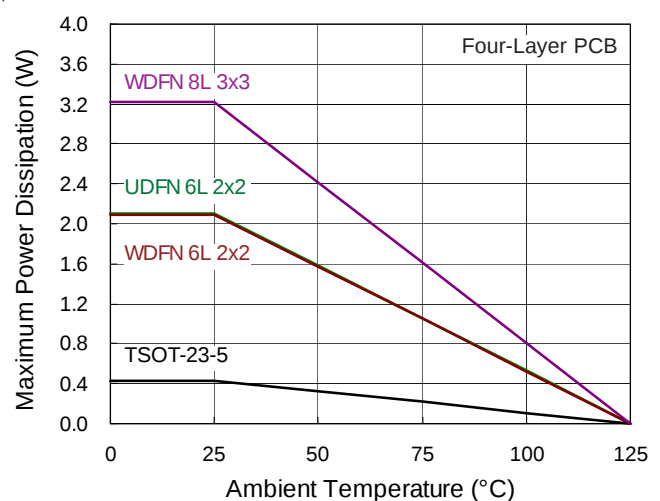


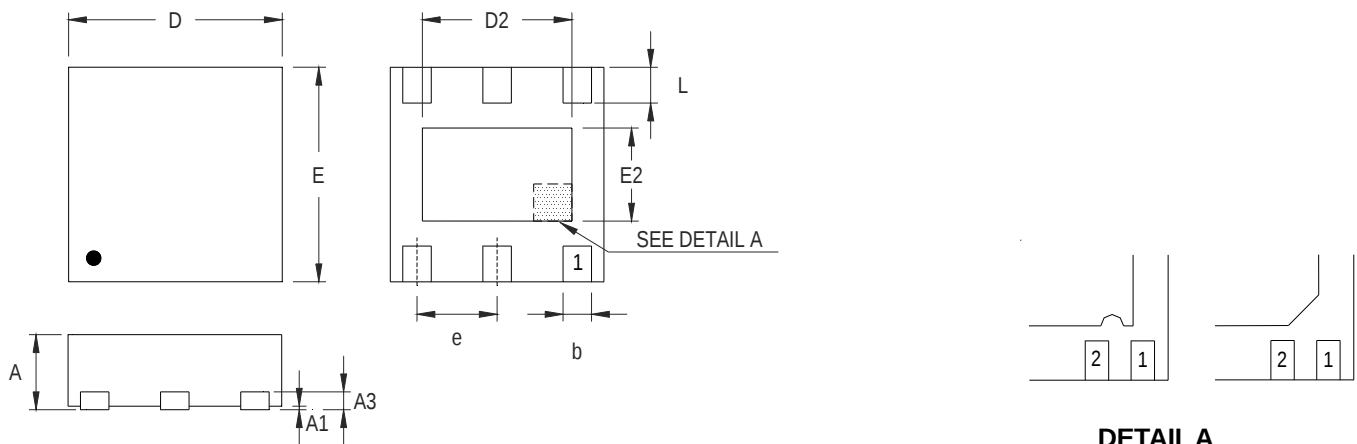
Figure 1. Derating Curve of Maximum Power Dissipation

Layout Consideration

PCB layout is very important for designing power converter circuits. The following layout guidelines should be strictly followed for best performance of the RT9148/9.

- ▶ Place the power components as close to the IC as possible. The traces should be wide and short, especially for the high current loop.
- ▶ A series resistance may be needed at the output for some applications.
- ▶ Connect a 0.1 μ F capacitor from VINx+ to ground and place it as close to the IC as possible for better performance.
- ▶ The exposed pad of the chip should be connected to a large PCB plane for maximum thermal consideration.

Outline Dimension



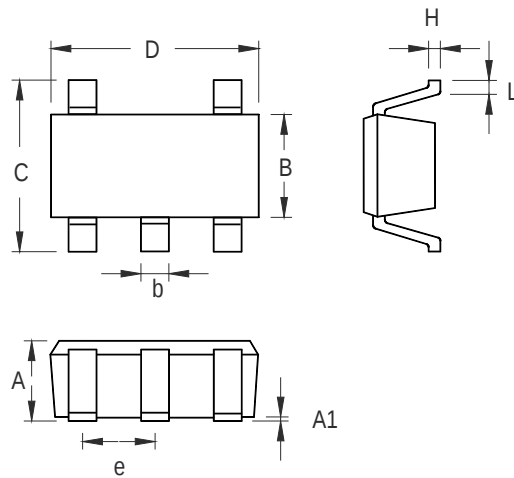
DETAIL A

Pin #1 ID and Tie Bar Mark Options

Note : The configuration of the Pin #1 identifier is optional, but must be located within the zone indicated.

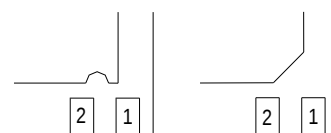
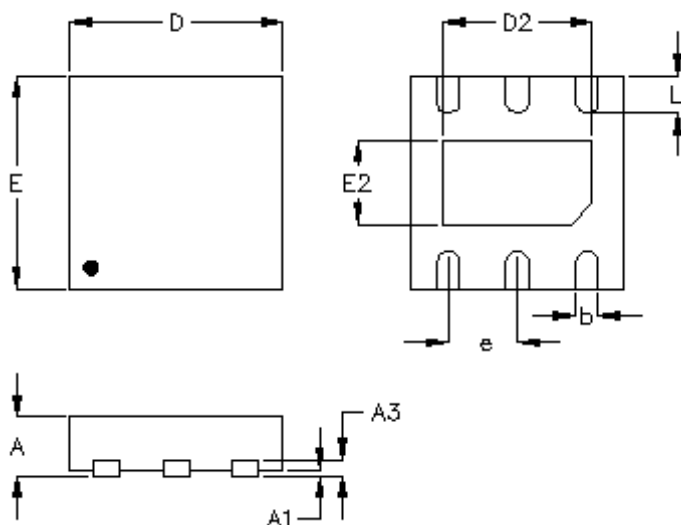
Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	Max	Min	Max
A	0.700	0.800	0.028	0.031
A1	0.000	0.050	0.000	0.002
A3	0.175	0.250	0.007	0.010
b	0.200	0.350	0.008	0.014
D	1.950	2.050	0.077	0.081
D2	1.000	1.450	0.039	0.057
E	1.950	2.050	0.077	0.081
E2	0.500	0.850	0.020	0.033
e	0.650		0.026	
L	0.300	0.400	0.012	0.016

W-Type 6L DFN 2x2 Package



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	Max	Min	Max
A	0.700	1.000	0.028	0.039
A1	0.000	0.100	0.000	0.004
B	1.397	1.803	0.055	0.071
b	0.300	0.559	0.012	0.022
C	2.591	3.000	0.102	0.118
D	2.692	3.099	0.106	0.122
e	0.838	1.041	0.033	0.041
H	0.080	0.254	0.003	0.010
L	0.300	0.610	0.012	0.024

TSOT-23-5 Surface Mount Package



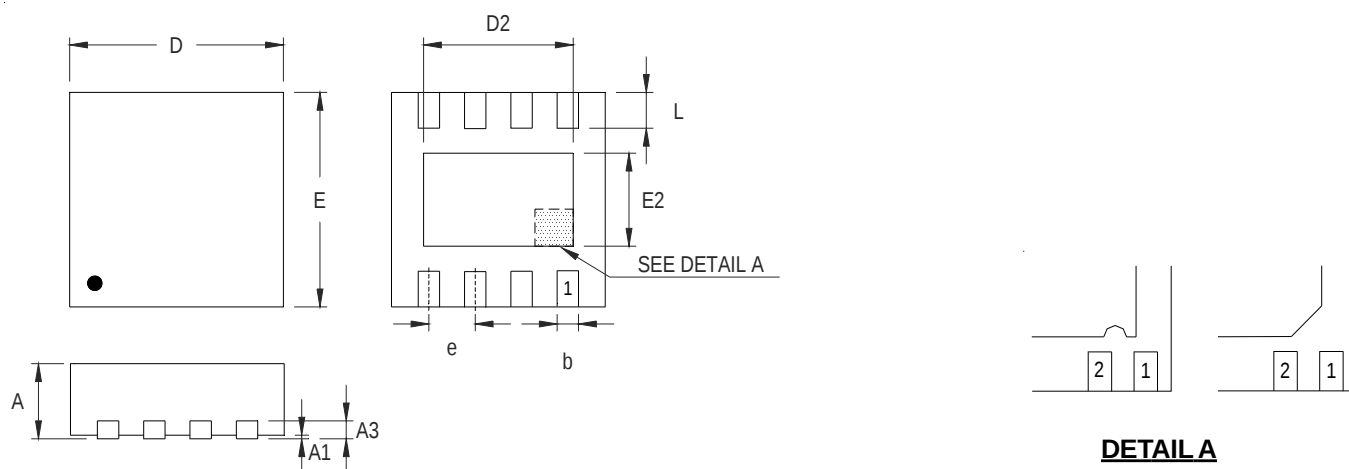
DETAIL A

Pin #1 ID and Tie Bar Mark Options

Note : The configuration of the Pin #1 identifier is optional, but must be located within the zone indicated.

Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min.	Max.	Min.	Max.
A	0.500	0.600	0.020	0.024
A1	0.000	0.050	0.000	0.002
A3	0.100	0.175	0.004	0.007
b	0.200	0.300	0.008	0.012
D	1.900	2.100	0.075	0.083
D2	1.350	1.450	0.053	0.057
E	1.900	2.100	0.075	0.083
E2	0.750	0.850	0.030	0.033
e	0.650		0.026	
L	0.300	0.400	0.012	0.016

U-Type 6L DFN 2x2 Package



DETAIL A

Pin #1 ID and Tie Bar Mark Options

Note : The configuration of the Pin #1 identifier is optional, but must be located within the zone indicated.

Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	Max	Min	Max
A	0.700	0.800	0.028	0.031
A1	0.000	0.050	0.000	0.002
A3	0.175	0.250	0.007	0.010
b	0.200	0.300	0.008	0.012
D	2.950	3.050	0.116	0.120
D2	2.100	2.350	0.083	0.093
E	2.950	3.050	0.116	0.120
E2	1.350	1.600	0.053	0.063
e	0.650		0.026	
L	0.425	0.525	0.017	0.021

W-Type 8L DFN 3x3 Package

Richtek Technology Corporation

14F, No. 8, Tai Yuen 1st Street, Chupei City

Hsinchu, Taiwan, R.O.C.

Tel: (8863)5526789

Richtek products are sold by description only. Richtek reserves the right to change the circuitry and/or specifications without notice at any time. Customers should obtain the latest relevant information and data sheets before placing orders and should verify that such information is current and complete. Richtek cannot assume responsibility for use of any circuitry other than circuitry entirely embodied in a Richtek product. Information furnished by Richtek is believed to be accurate and reliable. However, no responsibility is assumed by Richtek or its subsidiaries for its use; nor for any infringements of patents or other rights of third parties which may result from its use. No license is granted by implication or otherwise under any patent or patent rights of Richtek or its subsidiaries.